





# HIGH-VOLTAGE, MEDIUM-SENSITIVITY AUTOMOTIVE HALL-EFFECT LATCH

### **Description**

The AH3765Q is an AEC-Q100 qualified high-voltage, medium-sensitivity Hall-Effect latch IC designed for brushless DC-motor commutation, speed measurement, angular or linear encoders and position sensors in automotive applications. To support wide range of demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3765Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

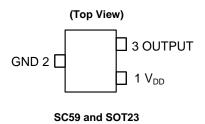
The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point ( $B_{op}$ ) the output is switched on (pulled low). The output is held latched until magnetic flux density reverses and becomes lower than the release point ( $B_{rp}$ ).

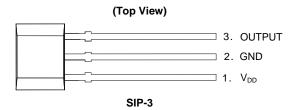
The magnetic operating and release polarity is opposite for SOT23 and SC59 packages. SOT23 and SIP-3 packages will require South pole to the part marking side to operate while SC59 will require South pole to the non-part-marking side.

#### **Features**

- · Bipolar Latch Operation (South Pole: On, North Pole: off)
- High Sensitivity: B<sub>op</sub> and B<sub>rp</sub> of +70G and -70G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- Chopper Stabilized Design Provides
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- · Reverse Blocking Diode
- · Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM >8kV, CDM: >2kV
- AEC-Q100 Grade 0 Qualified
- · Industry Standard SC59, SOT23 and SIP-3 Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Pin Assignments**





### **Applications**

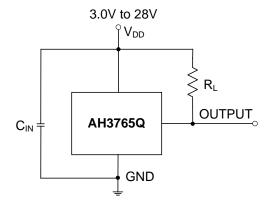
- Brushless DC-Motor Commutation
- · Revolution Per Minute (RPM) Measurement
- Angular and Linear Encoder and Position Sensing and Indexing
- Flow Meters
- Contactless Commutation, Speed Measurement and Angular Position Sensing/Indexing in Automotive Applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**



Note:

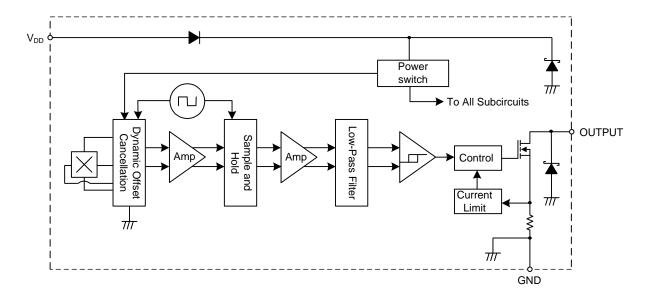
4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R<sub>L</sub> is the pull-up resistor.

### **Pin Descriptions**

#### Package: SC59, SOT23 and SIP-3

Pin Number	Pin Name	Function
1	$V_{DD}$	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

### **Functional Block Diagram**





#### Absolute Maximum Ratings (Notes 5 & 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
$V_{DD}$	Supply Voltage (Note 6)		32	V	
$V_{DDR}$	Reverse Supply Voltage (Note 6)		-32	V	
V <sub>OUT_MAX</sub>	Output Off Voltage (Note 6)		32	V	
I <sub>OUT</sub>	Continuous Output Current		60	mA	
I <sub>OUT_R</sub>	Reverse Output Current		-50 mA		
В	Magnetic Flux Density		Unlimited		
D-	Package Power Dissipation	SIP-3	550	mW	
P <sub>D</sub>	Fackage Fower Dissipation	SC59 and SOT23	230		
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand - Human Body Model (HM	MB)	8	kV	
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)		800	V	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model (	(CDM)	2	kV	

Notes:

- 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
- 6. The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

#### Recommended Operating Conditions (@T<sub>A</sub> = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
$V_{DD}$	Supply Voltage	Operating	3.0 to 28	V
T <sub>A</sub>	Operating Temperature Range	Operating	-40 to +150	°C

#### Electrical Characteristics (Notes 7 & 8) (@T<sub>A</sub> = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Vout_on	Output On Voltage	$I_{OUT} = 20\text{mA}, B > B_{op}$	-	0.2	0.4	V
I <sub>LKG</sub>	Output Leakage Current (when output is off)	V <sub>OUT</sub> = 28V, B < B <sub>rp</sub> , Output off	1	<0.1	10	μA
I <sub>DD</sub>	Supply Current	Output open, T <sub>A</sub> = +25°C	-	3	3.5	mA
		Output open, T <sub>A</sub> = -40°C to +150°C	-	-	4	mA
		$V_{DD} = -18V, T_A = +25^{\circ}C$	-	0.6	-	μΑ
I <sub>DD R</sub>	Reverse Supply Current	$V_{DD} = -18V$ , $T_A = -40$ °C to $+150$ °C	-	0.6	1,500	μΑ
א_טטי	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	-	μΑ
		$V_{DD} = -28V$ , $T_A = -40$ °C to $+150$ °C	-	1.6	2,500	μΑ
t <sub>P_ON</sub>	Device Power-On Time (start-up time)	$V_{DD} >= 3V, B > B_{op} (Note 7)$	-	10		μs
f <sub>c</sub>	Chopping Frequency	$V_{DD} >= 3V$	-	800	-	kHz
t <sub>d</sub>	Response Time Delay (time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	-	3.75	-	μs
t <sub>r</sub>	Output Rising Time (external pull-up resistor R <sub>L</sub> and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	-	0.2	1	μs
t <sub>f</sub>	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	ı	0.1	1	μs
locL	Output Current Limit	B > B <sub>op</sub> , (Note 10)	30	-	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5mA$	28	-	-	V

Notes:

- 7. When power is initially turned on, Vob must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 9. Guaranteed by design, process control and characterization. Not tested in production.
- 10. The device will limit the output current IOUT to current limit of IOCL.



# $\textbf{Magnetic Characteristics} \text{ (Notes 11 & 12) (T}_{A} = -40^{\circ}\text{C to } + 150^{\circ}\text{C}, \text{ V}_{DD} = 3.0\text{V to 28V, unless otherwise specified)}$

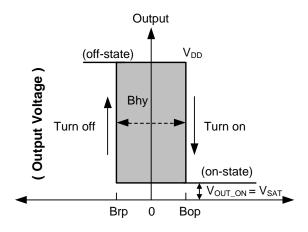
(1mT=10 Gauss)

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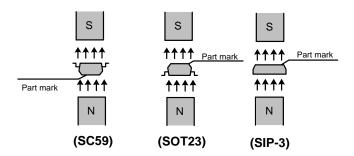
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
B <sub>ops</sub> (South pole to part marking side for		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	-	70	-	
SOT23 and SIP-3 packages; South pole to the non-part marking side for SC59 package. See diagram below)	Operation Point	T <sub>A</sub> = -40°C to +150°C	50	70	90	
B <sub>rps</sub> (North pole to part marking side for		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	-	-70	-	Gauss
SÖT23 and SIP-3 packages; North pole to the non-part marking side for SC59 package. See diagram below)	Release Point	T <sub>A</sub> = -40°C to +150°C	-90	-70	-50	Oauss
D. (ID. LID. I)	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25$ °C	-	140	-	
B <sub>hy</sub> ( B <sub>opx</sub>  - B <sub>rpx</sub>  )	Tiyoteteolo (Note 10)	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	100	140	180	

Notes:

- 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



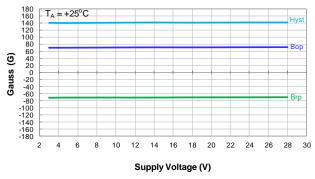
(Magnetic Flux Density B)



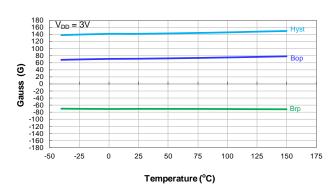


### **Typical Operating Characteristics**

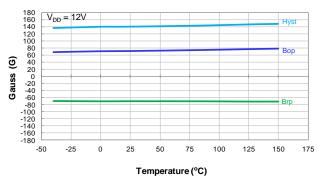
#### Output Switch Operate and Release Points (Magnetic Thresholds) – $B_{op}$ and $B_{rp}$



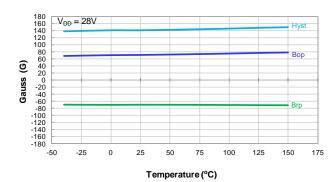
Switch Points Bop and Brp vs Supply Voltage



Switch Points Bop and Brp vs Temperature

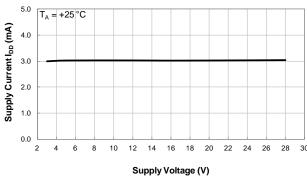


Switch Points Bop and Brp vs Temperature

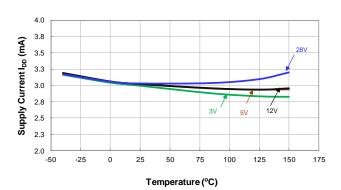


Switch Points Bop and Brp vs Temperature

#### **Supply Current**





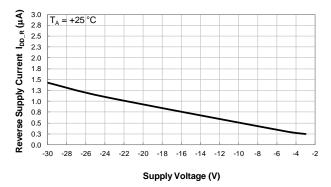


**Supply Current vs Temperature** 

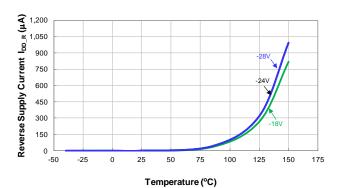


### **Typical Operating Characteristics (cont.)**

### **Reverse Supply Current**

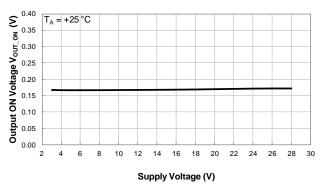


**Reverse Supply Current vs Supply Voltage** 

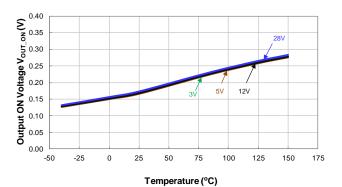


**Reverse Supply Current vs Temperature** 

#### **Output Switch On Voltage**

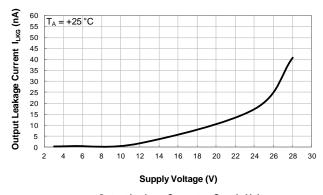


Output ON Voltage vs Supply Voltage

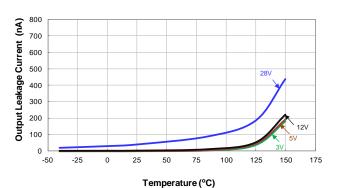


Output ON Voltage vs Temperature

#### **Output Switch Leakage Current**



Output Leakage Current vs Supply Voltage

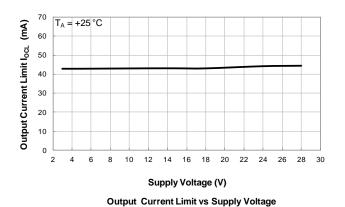


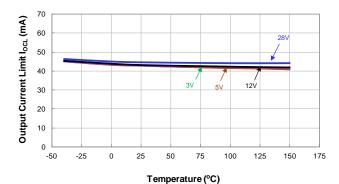
**Output Leakage Current vs Temperature** 



# **Typical Operating Characteristics (cont.)**

#### **Output Current Limit**





Output Current Limit vs Temperature

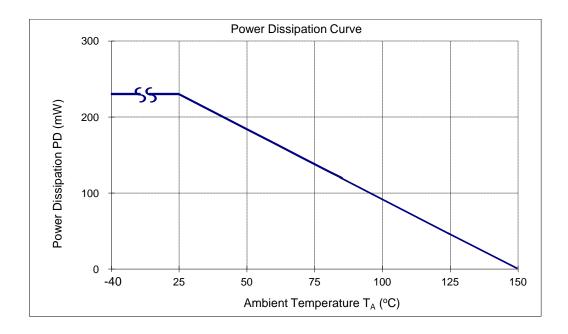
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### **Thermal Performance Characteristics**

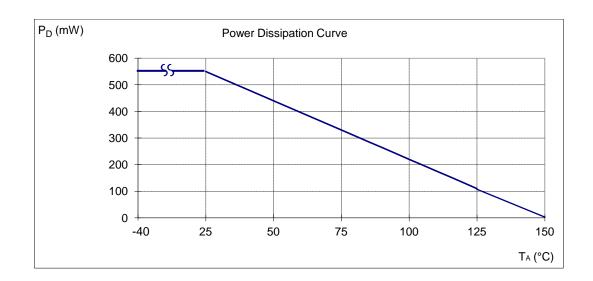
#### (1) Package type: SC59 and SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



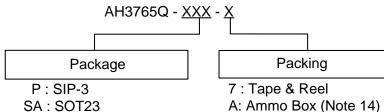
#### (2) Package type: SIP-3

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





### **Ordering Information**



W : SC59 B: Bulk (Note 15)

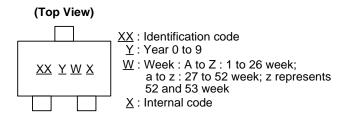
	Dockers		Bulk		7" Tape an	d Reel	Ammo Box	
Part Number	Package Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix
AH3765Q-P-A	Р	SIP-3	NA	NA	NA	NA	4,000/Box	-A
AH3765Q-P-B	Р	SIP-3	1,000	-B	NA	NA	NA	NA
AH3765Q-SA-7	SA	SOT23	NA	NA	3,000/Tape & Reel	-7	NA	NA
AH3765Q-W-7	W	SC59	NA	NA	3,000/Tape & Reel	-7	NA	NA

Notes: 14. Ammo Box is for SIP-3 Spread Lead.

15. Bulk is for SIP-3 Straight Lead.

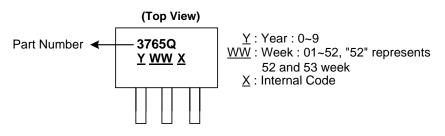
### **Marking Information**

#### (1) Package Type: SC59 and SOT23



Part Number	Package	Identification Code		
AH3765Q	SC59	YP		
AH3765Q	SOT23	WP		

#### (2) Package Type: SIP-3



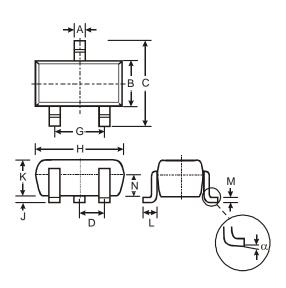
Part Number	Package	Identification Code		
AH3765Q	SIP-3	3765Q		



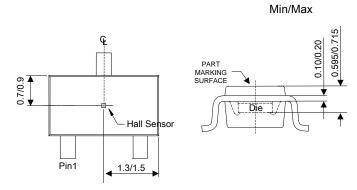
### Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (1) Package Type: SC59



	SC	59	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	-	-	0.95
G	-	-	1.90
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All	Dimens	ions in	mm



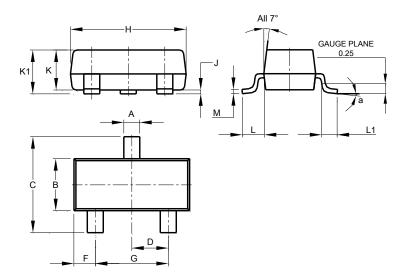
**Sensor Location** 



### Package Outline Dimensions (cont.) (All dimensions in mm.)

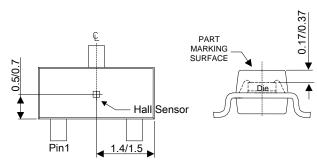
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (2) Package Type: SOT23



	so	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а		8°	
All	Dimens	ions in	mm

### Min/Max



Sensor Location - To be updated

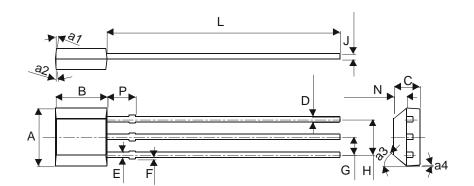


### Package Outline Dimensions (cont.) (All dimensions in mm.)

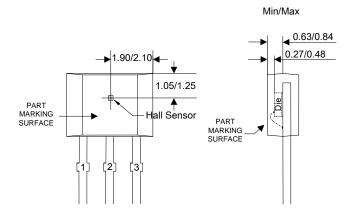
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (3) Package Type: SIP-3 Bulk

Sensor location to be added



SIP-3 (Bulk)			
Dim	Min	Max	
Α	3.9	4.3	
a1	5° Typ		
a2	5°Typ		
а3	45° Typ		
a4	3°Тур		
В	2.8	3.2	
С	1.40	1.60	
D	0.33	0.432	
Е	0.40	0.508	
F	0	0.2	
G	1.24	1.30	
Н	2.51	2.57	
7	0.35	0.43	
L	14.0	15.0	
N	0.63	0.84	
Р	1.55	-	
All Dimensions in mm			



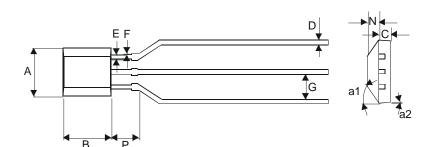
Sensor Location - To be updated



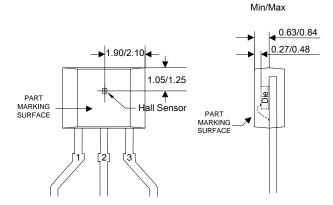
### Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### (4) Package Type: SIP-3 Ammo Pack



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Typ	
В	2.8	3.2
C	1.40	1.60
D	0.35	0.41
Е	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	=
All Dimensions in mm		



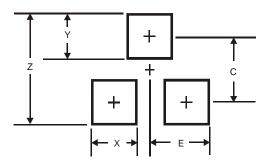
Sensor Location - To be updated



# Suggested Pad Layout

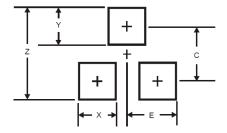
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### (1) Package Type: SC59



Dimensions	Value (in mm)
Z	3.4
X	0.8
Y	1.0
С	2.4
E	1.35

#### (2) Package Type: SOT23



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
Е	1.35



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  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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